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(54) Organic electroluminescence display device

Organische Elektrolumineszente Anzeigevorrichtung

Dispositif d'affichage électroluminescent organique

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Description

[0001] The present invention relates to organic electroluminescence (EL) display devices, and more particularly, to an organic EL display device with improved light bleeding efficiency of light emitted from an organic film.

[0002] Organic EL display devices are spontaneous light-emitting display devices that emit light by electrically exciting a fluorescent organic compound. Typically, organic EL display devices may operate at a low voltage, be formed compactly to form a thin device, and provide a wide viewing angle and a high response speed. Organic EL display devices are the focus of considerable attention because they may be used as next-generation display devices that are free of the problems of liquid crystal display devices.

[0003] In such organic EL display devices, a predetermined pattern of organic films is formed on glass or a transparent insulative substrate, and electrode layers are formed on the top and bottom surfaces of the organic film pattern. The organic films may be made of various organic compounds such as copper phthalocyanine (CuPc), N, N'-Di (naphthalene-1-yl)-N, N'-diphenyl-benzidine (NPB), and tris-8-hydroxyquinoline aluminum (Alq3).

[0004] In organic EL display devices having the above-described structure, as positive and negative voltages are applied to electrodes, filled holes migrate from electrodes to which the positive voltage is applied to a luminescent layer via a hole transport layer and electrons migrate from electrodes to which the negative voltage is applied to the luminescent layer via the hole transport layer. In the luminescent layer, the holes and the electrons re-unite to generate excitons. As the excitons de-excite, fluorescent molecules in the luminescent layer emit light, thus forming an image.

[0005] The light efficiency of organic EL display devices driven as described above includes internal efficiency and external efficiency (or light bleeding efficiency). Internal efficiency relates to the efficiency of photoelectric conversion of an organic luminescent material, and external efficiency depends on the refractive indices of the layers that constitute the organic EL display device. In other words, when light is emitted from the organic films at a critical angle or greater, the emitted light is reflected at the interface between the substrate and the electrode layers or between the organic films and the electrode layers. Thus, the emitted light is prevented from being bled off.

[0006] In a conventional organic EL display device, as shown in FIG. 1, when light emitted from an organic film 13, which is protected by a metal cathode layer 14, is transmitted through an interface between indium tin oxide (ITO) electrodes 12 and a transparent glass substrate 11, to the transparent glass substrate 11, the light transmittance T is given by: $T = 1/2(n_{\text{glass}}/n_{\text{ITO}})^2$, wherein n_{glass} denotes the refractive index of glass and n_{ITO} denotes the refractive index of ITO.

[0007] Based on the above equation, the light bleeding efficiency for individual colors of a conventional organic EL display device is shown in the following table.

	Blue organic film	Red organic film	Green organic film
Wavelength (nm)	460	620	530
Refractive index (n) of ITO electrodes	2.01	1.76	1.93
Refractive index (n) of glass substrate	1.525	1.515	1.52
Light bleeding efficiency	29%	37%	34%

[0008] As shown in the above table, 60% or more of the light generated in an organic EL display device is extinguished within the device due to the difference between the refractive indices of the ITO electrodes and the glass substrate.

[0009] Japanese Patent Publication No. hei 11-283751 discloses an organic EL display device having a structure in which a diffraction grating or a zone plate is formed on a substrate to diffract light guided by ITO electrodes and by an interface between organic films and the ITO electrodes, thus reducing light loss. Since this organic EL display device requires a wavy substrate, a wavy fine electrode pattern layer, or a special diffraction grating, its manufacturing process is complicated. Also, when an organic layer is formed on the wavy surface or the diffraction grating, the surface illumination of the organic layer increases. Thus, the leakage current of the organic EL display device increases and durability and reliability decrease.

[0010] An example of a conventional organic EL display device which prevents degradation of light bleeding efficiency is disclosed in Japanese Patent Publication No. sho 63-172691. The disclosed organic EL display device includes a condensed substrate such as a substrate on which a protrusion lens is installed. However, since pixels depending on the luminescence of an organic film are very small, it is difficult to install the protrusion lens for condensing on the substrate.

[0011] Japanese Patent Publication No. hei 1-220394 discloses an organic EL display device in which lower electrodes, an insulating layer, a luminescent layer, and upper electrodes are formed on a substrate, and a mirror that reflects light is installed on a single face of the luminescent layer. In this organic EL display device, since the luminescent layer is very thin, it is very difficult to install a reflective mirror on one side of the luminescent layer.

[0012] However, Japanese Patent Publication No. hei 9-171892 discloses an organic EL display device in which anodes and an anode interface layer are formed on a glass substrate having a lens-shaped structure installed thereon, and a hole transport layer, a luminescent layer, an electron transport layer, cathodes, and an anode protective layer are formed on the resulting glass substrate. In this organic EL display device, since reflected light bleeds toward the glass substrate, the bleeding efficiency increases, but images become blurred.

[0013] Japanese Patent Publication No. hei 10-12382 discloses an organic EL display device that has a light guide formed between front electrodes of an organic luminescent device and a group of small lenses incorporated into the front surface of the light guide, such that emitted light is guided to the front electrodes, and light bleeds evenly.

[0014] U.S. Patent Publication No. 2001/0019242 A1 also discloses an organic EL display device and a method of manufacturing the same.

[0015] Lupton, J. M. et al: "Bragg scattering from periodically microstructured light emitting diodes", Applied Physics Letters, vol. 77, no. 21, pages 3340 to 3342, 20 November 2000, discloses an electroluminescent display device in which an electroluminescent layer, an electrode and a photoresist layer are each provided with a photonic crystal structure. The photonic structure provides increased light intensity.

[0016] US 6476550 B1 and EP 1116987 A2 disclose electroluminescent display devices having diffraction gratings and polarized light scattering films, respectively.

[0017] Japanese Patent Publication No. 10-111522 discloses a liquid crystal display device having a light scattering plate scatter emitting reflected light reflected from the rear toward the front.

[0018] European patent application publication number EP 1096579 A2 discloses an organic EL device having a structure in which an EL layer is sandwiched between a transparent electrode and a cathode.

[0019] According to the invention, there is provided an organic electroluminescence display device assembly according to claim 1

[0020] According to an embodiment of the present invention, an organic electroluminescence (EL) display device assembly includes a substrate, an organic EL portion, an optical loss prevention layer, and a fine space layer. The organic EL portion has a first electrode layer, an organic luminescent layer, and a second electrode layer, which are each patterned and stacked on the upper surface of the substrate. The optical loss prevention layer increases light bleeding efficiency. The fine space layer is formed between the optical loss prevention layer and a layer facing the optical loss prevention layer and is filled with a gas or evacuated.

The optical loss prevention layer is a diffraction grating forming unit with a plurality of protrusions which form a pattern.

[0021] According to another embodiment of the present invention, an organic EL display device assembly includes a substrate, an organic EL display portion, a photonic plate, and a fine space layer. The organic EL display portion has a first electrode layer, an organic luminescent layer, and a second electrode layer, which are each patterned and stacked on the upper surface of the substrate. The photonic plate is combined with the organic EL display portion and has an optical loss prevention layer formed over the organic EL display portion. The fine space layer is formed between the optical loss prevention layer and the photonic plate and increases the light bleeding efficiency of light generated by the organic luminescent layer.

[0022] According to still another embodiment of the present invention, an organic EL display device assembly includes a substrate, first and second electrode layers, an organic luminescent layer, an optical loss prevention layer, and a space layer. The first electrode layer, the organic luminescent layer, and the second electrode layer are sequentially stacked on the upper surface of the substrate. The optical loss prevention layer is formed between layers having a substantial difference in the refractive index among the first and second electrode layers and the organic luminescent portion, and has areas with different refractive indices. The space layer is formed between the optical loss prevention layer and a layer facing the optical loss prevention layer and is filled with a gas or evacuated.

[0023] According to still yet another embodiment of the present invention, an organic EL display device assembly includes a substrate, a pixel portion, a driving portion, and a photonic plate. The pixel portion has a first electrode layer patterned on the substrate, an organic luminescent layer patterned on the upper surface of the first electrode layer, an insulating layer formed on the upper surface of the substrate to expose the organic luminescent layer, and a second electrode layer which is transparent and patterned on the upper surface of the organic luminescent layer and the upper surface of the insulating layer. The driving portion is formed on the substrate and has thin film transistors for switching the first electrode layer. The photonic plate is located on the upper surface of the transparent second electrode layer to form a fine space layer that is filled with an inert gas or evacuated and is located between the photonic plate and the second electrode layer, and has an optical loss prevention layer formed on the inside surface of the photonic plate.

[0024] According to yet another embodiment of the present invention, an organic EL display device assembly includes a substrate, a pixel portion, a driving portion, an optical loss prevention layer, and a photonic plate. The pixel portion has a first electrode layer patterned on the substrate, an organic luminescent layer patterned on the upper surface of the first electrode layer, an insulating layer formed on the upper surface of the substrate to expose the organic luminescent layer, and a second electrode layer which is transparent and patterned on the upper surface of the organic luminescent layer and the upper surface of the insulating layer. The driving portion is formed on the substrate and has thin film

transistors for switching the first electrode layer. The optical loss prevention layer is formed between the substrate and the first electrode layer and has patterned areas with different refractive indices. The space layer is filled with an inert gas or evacuated and formed between the optical loss prevention layer and a layer facing the optical loss prevention layer.

[0025] According to an embodiment of the present invention, an organic EL display device assembly is utilized in a computer.

Additional aspects and/or advantages of the invention will be set forth in part in the description which follows and, in part, will be obvious from the description, or may be learned by practice of the invention.

[0026] The present invention thus provides an organic EL display device assembly which reduces internal optical loss and increases light bleeding efficiency to increase the luminance of an image.

[0027] The present invention also provides an organic EL display device which reduces optical loss using a scattering efficiency at an interface between a layer with a high refractive index and a layer with a low refractive index.

[0028] These and/or other aspects and advantages of the invention will become apparent and more readily appreciated from the following description of the embodiments, taken in conjunction with the accompanying drawings of which:

FIG. 1 is a cross-sectional view for illustrating light bleeding that occurs in a conventional organic EL display device; FIG. 2 is a cross-section of an organic EL display device assembly according to a first embodiment of the present invention;

FIG. 3 is a magnified cross-section of the organic luminescent layer of FIG. 2;

FIG. 4 is a cross-section of an organic EL display device assembly according to a second embodiment of the present invention;

FIGS. 5 and 6 are cross-sections of organic EL display device assemblies according to third and fourth embodiments of the present invention;

FIGS. 7 and 8 are cross-sections of organic EL display device assemblies according to fifth and sixth embodiments of the present invention;

FIGS. 9 through 12 are cross-sections of organic EL display device assemblies according to seventh through tenth embodiments of the present invention;

FIG. 13 is a graph showing optical efficiency versus a gap between an optical loss prevention layer and an electrode layer;

FIG. 14 is a graph showing optical efficiency versus the length of the optical loss prevention layer;

FIG. 15 is a graph showing optical efficiency versus the depth of an index layer of TiO_2 in an organic EL display device assembly;

FIG. 16 is a representation of an example of a desktop computer utilizing an organic EL display device assembly in accordance with an embodiment of the present invention; and

FIG. 17 is a representation of an example of a laptop computer utilizing an organic EL display device assembly in accordance with an embodiment of the present invention.

[0029] Reference will now be made in detail to the present embodiments of the present invention, examples of which are illustrated in the accompanying drawings, wherein like reference numerals refer to the like elements throughout. The embodiments are described below in order to explain the present invention by referring to the figures.

[0030] An organic EL display device according to the present invention improves the bleeding efficiency of light emitted from an organic luminescent layer. FIG. 2 shows a magnified part of an organic EL display device assembly 20 according to an embodiment of the present invention.

[0031] Referring to FIG. 2, the organic EL display device assembly 20 includes first and second electrode layers 22 and 23 and an organic luminescent layer 30. The first electrode layer 22 is transparent and is formed on the upper surface of a transparent substrate 21 in a predetermined pattern. The organic luminescent layer 30 is formed by stacking organic films on the upper surface of the first electrode layer 22. The second electrode layer 30 is formed on the upper surface of the organic luminescent layer 30 and has a predetermined pattern.

[0032] The first electrode layer 22 is an anode formed on/proximate to the upper surface of the transparent substrate 21 and may be made of indium tin oxide (ITO); which is a transparent conductive material. The second electrode layer 23 may be formed of a conductive metal such as aluminium, an aluminium alloy, silver, or a silver alloy.

[0033] As shown in FIG. 3, the organic luminescent layer 30 is formed by sequentially stacking a hole implantation layer 31, a hole transport layer 32, a luminescent layer 33, and an electron implantation layer 34 on the upper surface of the first electrode layer 21. Preferably, the organic luminescent layer 30 is formed of a low polymer organic compound, such as tris-8-hydroxyquinoline aluminum (Alq3), or a high polymer organic compound, such as, poly(paraphenylenevinylene) (PPV) or poly(2-Methoxy-5-(2-Ethylhexyloxy)-1,4-phenylenevinylene). However, the material of the organic luminescent layer 30 is not limited to these materials.

[0034] An optical loss prevention layer 100 for improving light bleeding efficiency is formed on the upper surface of the transparent substrate 21. A fine space layer 50, which is filled with a gas or evacuated, is formed between the optical

loss prevention layer 100 and the first electrode layer 22.

[0035] The optical loss prevention layer 100 is a diffraction grating which may have a plurality of protrusions 111 each having a predetermined pitch (P) and a predetermined height (H). Preferably, the pitch P of the protrusions 111 of the diffraction grating is 200 nm to 2000 nm, and the height H thereof is 50 nm to 5000 nm. Each of the protrusions 111 may have various shapes, such as, a circular cylindrical shape, or a multilateral pyramidal shape. The protrusions 111 may have any shape as long as they protrude to have a predetermined pattern. Alternatively, a thin film having a plurality of through holes for a diffraction grating may be formed on the upper surface of the transparent substrate 21.

[0036] The optical loss prevention layer 100, which is a diffraction grating, may be formed of at least one material selected from the group consisting of SiO_x ($x > 1$), SiN_x , Si_3N_4 , TiO_2 , MgO , ZnO , Al_2O_3 , SnO_2 , In_2O_3 , MgF_2 , and CaF_2 . Preferably, the optical loss prevention layer 100 is formed of TiO_2 .

[0037] The fine space layer 50 may be formed in such a way that the protrusions 111 of the diffraction grating are closely adhered to the first electrode layer 22 and to the side on which the first electrode layer 22 is formed. Also, extra spacers (not shown) may be included in the fine space layer 50.

[0038] On the other hand, as shown in FIG. 4, instead of the optical loss prevention layer 100, a patterned thin film 120 may be formed to have first and second areas formed of at least two materials with different refractive indices. Preferably, the pitch (P) of one of the two areas arranged in a predetermined pattern is 200 nm to 2000 nm corresponding to the pitch of the protrusions 111, and the thickness (T) of the thin film 120 is 0.01 μm to 50 μm . In the embodiment of FIG. 4, the first and second electrode layers 22 and 23 and the organic luminescent layer 30 are formed on an extra upper substrate 25.

[0039] In the above-described embodiments, as shown in FIGS. 5 and 6, an index layer 60 with a refractive index higher than the refractive indices of the fine space layer 50 and the first electrode layer 22 may be formed between the fine space layer 50 and the first electrode layer 22. Preferably, the index layer 60 is formed of a material with a refractive index of 2.3 or greater, for example, TiO_2 . However, the material of the index layer 60 is not limited to a material with a refractive index of 2.3 or greater.

[0040] As shown in FIGS. 7 and 8, an organic EL display device assembly includes an organic EL display portion 70, which has a first electrode layer 72 formed on a substrate 71, an organic luminescent layer 73 formed on the first electrode layer 72 to have a predetermined pattern, and a second electrode layer 74 formed of a transparent conductive metal on the organic luminescent layer 73. The organic EL display portion 70 is combined with a photonic plate 200 on which an optical loss prevention layer 210 or 220 is formed and the fine space layer 50 is formed between the organic EL display portion 70 and the photonic plate 200.

[0041] As shown in FIG. 7, the optical loss prevention layer 210 formed on the photonic plate 200 is comprised of protrusions 211, each having a predetermined height. Alternatively, as shown in FIG. 8, the optical loss prevention layer 220 is a thin film having first and second areas formed of two materials with different refractive indices. Here, at least one of the first and second areas is patterned. The first areas of the optical loss prevention layer 220 may be arranged in dots, but the first areas are not limited to such an arrangement. Preferably, the difference between the refractive indices of the materials of the first and second areas is no less than 0.3 and no more than 3. More preferably, the refractive index difference is as large as possible within the range of 0.3 to 3. If the refractive index difference is less than or equal to 0.3, the interface between the organic luminescent layer and each of the electrode layers provides a low scattering efficiency. Thus, the reflexivity of light emitted from the organic luminescent layer increases, and accordingly, the amount of light bleeding while penetrating the substrate decreases.

[0042] FIGS. 9 and 10 illustrate embodiments of an active matrix (AM) organic EL display device assembly 150, which are organic EL display device assemblies according to different embodiments of the present invention. Referring to FIG. 9, the AM organic EL display device assembly 150 includes a buffer layer 152, a pixel area 160, and a driving area 170. The buffer layer 152 is formed on a transparent substrate 151. The pixel area 160 includes pixels and a second electrode layer 161 for forming the pixels and is formed over the buffer layer 152. The driving area 170 includes a thin film transistor (TFT) and a capacitor 177 that are used to drive the pixel area 160, and is formed over the buffer layer 152.

[0043] In the driving area 170, a semiconductor layer 171 doped with p- or n-type impurities is formed on the upper surface of the buffer layer 152 to have a predetermined pattern, and is buried under a gate insulating layer 172. A gate electrode layer 173 is formed on the upper surface of the gate insulating layer 172 and opposite to the semiconductor layer 171. A first insulating layer 174 is also formed on the upper surface of the gate insulating layer 172 and covers the gate electrode layer 173. The thin film transistor is composed of drain and source electrodes 175 and 176 formed on the upper surface of the first insulating layer 174. Here, drain and source electrodes 175 and 176 are partially connected to both ends of the semiconductor layer 171 through contact holes 175a and 176a formed through the first insulating layer 174 and the gate insulating layer 172. The capacitor 177 includes first auxiliary electrodes 177a that are connected to the source electrodes 176 and are formed on the upper surface of the first insulating layer 174, and second auxiliary electrodes 177b that are opposite to the first auxiliary electrodes 177a and are buried under the first insulating layer 174. A second insulating layer 178 for achieving smoothing is formed on the upper surface of the first insulating layer 174 having the drain and source electrodes 175 and 176 formed thereon.

[0044] In the pixel area 160, a second electrode layer 161 is formed on the upper surface of the second insulating layer 178 to have a predetermined pattern and to be electrically connected to the second insulating layer 178 through a conductive connector 161a formed within the second insulating layer 178. An organic luminescent layer 162 is formed on the upper surface of the second electrode layer 161 to have a predetermined pattern. A first transparent electrode layer 163 is formed on the organic luminescent layer 162. A third insulating layer (not shown) for achieving planarization may be formed on the upper surface of the second insulating layer 178 on which the first electrode layer 163 has been formed. Preferably, the third insulating layer is formed of a transparent material that does not interfere with the bleeding of light emitted from the organic luminescent layer 162.

[0045] The photonic plate 200 on which the optical loss prevention layer 100 is formed is attached to the third insulating layer of the organic EL display device assembly, thus forming the fine space layer 50 between the third insulating layer and the photonic plate 200. As described above, the fine space layer 50 may be filled with an inert gas or evacuated. As shown in FIG. 9, the optical loss prevention layer 100 on the photonic plate 200 may be composed of protrusions 111 with a predetermined pitch and a predetermined height. Alternatively, as shown in FIG. 10, the optical loss prevention layer 100 may be a thin film formed of different materials with different refractive indices to have first and second areas.

[0046] As shown in FIGS. 11 and 12, an index layer 60 may be further formed on the upper surface of the third insulating layer (not shown). Since the structures of the optical loss prevention layer 100 and the index layer 60 are the same as described in the previous embodiments, they will not be described here in greater detail.

[0047] The locations of the optical loss prevention layer and the fine space layer are not limited to the above-described embodiments. The optical loss prevention layer and the fine space layer may be formed between layers with high refractive indices on a path where light emitted from the organic luminescent layer bleeds. For example, in rear luminescence type organic EL display devices, an optical loss prevention layer and a fine space layer are formed on a substrate.

[0048] In organic EL display device assemblies having structures as in the above-described embodiments, when a predetermined voltage is applied thereto to illuminate selected pixels on the first electrode layer 22 or 72 and the second electrode layer 23 or 74, holes introduced from the first electrode layer 22 or 72, which is an anode, move to the hole transport layer 32 via the hole injection layer 31, while electrons are filled into the luminescent layer 33 via the electron injection layer 34. The electrons and holes are re-united in the luminescent layer 33 to create excitons. As the excitons de-excite, fluorescent molecules in the organic luminescent layer 30 or 73 emit light. The generated light bleeds to the outside via the first electrode layer 22 or 72, the optical loss prevention layer 100, and the fine space layer 50.

[0049] Because the optical loss prevention layer 100, 210, or 220 and the fine space layer 50 are formed of ITO between the first electrode layer 22 or 72 and the substrate 21 or 71 or between the third insulating layer (not shown) and the photonic plate 200, optical loss due to the reflection of light at the interface between the substrate and the electrode layer may be reduced.

[0050] In other words, since the refractive index of the organic luminescent layer 30 (or 70) or the first electrode layer 22 (or 72) is higher than the refractive index of the second insulating layer or glass for the fine space layer 50, light is reflected at the interface between the substrate 21 (or 71) and the first electrode layer 22 (or 72). However, because the fine space layer 50 and the optical loss prevention layer 100 (or 210 or 220) are formed between the first electrode layer 22 (or 72) and the substrate 21 (or 71) or between the third insulating layer (not shown) and the photonic plate 200, the first electrode layer 22 (or 72) and the protrusions 111 of the optical loss prevention layer 100 (or 210 or 220) cause evanescent wave coupling. Accordingly, the fine space layer 50 between the first electrode layer 22 and each of the protrusions 111 generates evanescent waves. Thus, part of light guided by the first electrode layer 22 is transported to and diffracted by the optical loss prevention layer 100. Consequently, light bleeding efficiency increases.

[0051] If the thin film 120 having first and second areas defined by patterning two different materials with different refractive indices is adopted as an optical loss prevention layer, the first and second areas cross each other. Accordingly, the mean refractive index of the optical loss prevention layer may be adjusted to a refractive index that may widen a total reflection angle. Thus, an anti-reflection occurs to improve the light bleeding efficiency.

[0052] The following experiments were performed to compare the amount of light bleeding in an organic EL display device having the fine space layer 50 and the optical loss prevention layer 100 (or 210 or 220), the amount of light bleeding in an organic EL display device having only the optical loss prevention layer 100 (or 210 or 220), and the amount of light bleeding in an organic EL display device having neither fine space layers nor optical loss prevention layers.

First experiment

[0053] The first experiment was performed on an organic EL display device in which an optical loss prevention layer having cylindrical protrusions was formed of SiO_2 , TiO_2 , and SiN_x on the upper surface of a substrate. The pitch between adjacent protrusions was in the range of 200 nm to 2000 nm, and the height of each of the protrusions was in the range of 50 nm to 5000 nm.

[0054] A first electrode layer, an organic luminescent layer, and a second electrode layer were sequentially stacked

on the upper surface of the resulting substrate and between the resulting substrate and a fine space layer. FIG. 13 is a graph of a measured optical efficiency versus the width of the gap of the fine space layer. FIG. 14 is a graph of optical efficiency versus the length of the cylindrical protrusions.

[0055] Through the first experiment, standardized optical energy values were calculated for different widths of the gap of the fine space layer using a Finite Difference Time Domain (FDTD) simulation. In other words, the standardized optical energy values were calculated by comparison with the optical energy value of an organic EL display device used in a first comparative experiment to be described later.

[0056] As shown in FIG. 13, when the width of the gap of the fine space layer is 0, that is, when the upper surface of each of the protrusions contacts the first electrode layer, the amount of light bleeding to the outside was four times greater than the amount of light bleeding in a conventional organic EL display device. As the width of the gap of the fine space layer increases, the optical efficiency, that is, the amount of light bleeding, decreases.

[0057] Also, when the protrusions of the optical loss prevention layer were formed of SiO_2 , the absolute amount of light bleeding was 2.41 times greater than that of the conventional organic EL display device. When the protrusions of the optical loss prevention layer were formed of TiO_2 , the absolute amount of light bleeding was 3.90 times greater than that of the conventional organic EL display device. When the protrusions of the optical loss prevention layer were formed of SiN_x , the absolute amount of light bleeding was 3.67 times greater than that of the conventional organic EL display device.

[0058] As shown in FIG. 14, the optical efficiency is proportional to the height of each of the protrusions up to a height of about 200 nm.

Second experiment

[0059] The second experiment was performed on an organic EL display device in which an index layer was formed of TiO_2 with a refractive index of 2.36 between the fine space layer and the first electrode layer under the same conditions as in the first experiment. FIG. 15 is a graph of optical efficiency versus the thickness of the index layer. Here, the gap of the fine space layer was 0, and the protrusions of the optical loss prevention layer were 400 nm high.

[0060] According to FIG. 15, when the thickness of the index layer was 50 nm, the optical efficiency increased by about 4 times and the amount of light bleeding increased by 47.1 % compared to the organic EL display device of the first comparative experiment.

First comparative experiment

[0061] The first comparative experiment was performed on an organic EL display device in which a first electrode layer, an organic luminescent layer, and a second electrode layer were simply formed on the upper surface of a transparent substrate.

[0062] In the organic EL display device, the amount of light guided by the transparent substrate was 34.9% of the amount of light guided to the organic luminescent layer, the amount of light reflected by the interface between the first and second electrode layers was 42.8% of the amount of light guided to the organic luminescent layer, and the amount of light bled to the outside was 22.3% of the amount of light guided to the organic luminescent layer.

Second comparative experiment

[0063] A second comparative experiment was performed on an organic EL display device in which a first electrode layer, an organic luminescent layer, and a second electrode layer were formed on the upper surface of a substrate, and a diffraction grating (i.e., optical loss prevention layer) was formed on the layer having the greatest refractive index among the first and second electrode layers and the organic luminescent layer. The diffraction grating was formed of SiO_2 or TiO_2 to have a plurality of protrusions each having a predetermined pitch.

According to the second comparative experiment, when the diffraction grating was formed of SiO_2 , the amount of light bleeding was 2.37 times that of the organic EL display device used in the first comparative experiment. When the diffraction grating was formed of TiO_2 , the amount of light bleeding was 2.38 times that of the organic EL display device used in the first comparative experiment.

[0064] In organic EL display device assemblies having the above-described structures, a fine space layer is formed between an optical loss prevention layer and an electrode layer, thereby reducing internal optical loss and accordingly increasing light bleeding efficiency. In particular, light bleeding may be increased by preventing reflection from occurring among a first electrode layer, an organic luminescent layer, and a second electrode layer. Also, suppression of bleeding of light reflected by a substrate may prevent blurring of images formed by the organic EL display device assemblies.

[0065] FIG. 16 is a representation of an example of a desktop computer 300 utilizing an organic EL display device assembly 304 in accordance with an embodiment of the present invention. The desktop computer 300 comprises a

central processing unit 302 as is known in the art and an organic electroluminescence (EL) display device assembly 304 as described more fully above.

[0066] FIG. 17 is a representation of an example of a laptop computer 402 utilizing an organic EL display device assembly 404 in accordance with an embodiment of the present invention. The laptop computer 402 comprises a central processing unit 408 as is known in the art and an organic electroluminescence (EL) display device assembly 404 as described more fully above. A keyboard 406 may be implemented to input data.

[0067] Although a few embodiments of the present invention have been shown and described, it would be appreciated by those skilled in the art that changes may be made in this embodiment without departing from the invention, the scope of which is defined in the claims.

Claims

1. An organic electroluminescence display device assembly comprising:

a substrate (21; 71); and
 an organic electroluminescence portion having a first electrode layer (22; 72), an organic luminescent layer (30; 73), and a second electrode layer (23; 74), which are each patterned and stacked on an upper surface of the substrate (21; 71); and
 a diffraction grating (100; 120; 210; 220) stacked on or proximate to the upper surface of the substrate above or below the organic electroluminescence portion arranged to function as an optical loss prevention layer to increase light bleeding efficiency;
characterized in that a fine space layer (50) filled with a gas or evacuated is formed between the diffraction grating (100; 120; 210; 220) and the organic electroluminescence portion.

2. The organic electroluminescence display device assembly of claim 1, wherein the first electrode layer (22), the organic luminescent layer (30), and the second electrode layer (23) are each patterned and stacked proximate to an upper surface of the substrate (21).

3. The organic electroluminescence display device assembly of claim 2, wherein the diffraction grating (100) has a plurality of protrusions (111) formed on the upper surface of the substrate (21) with a predetermined pitch (P) between adjacent protrusions (111).

4. The organic electroluminescence display device assembly of claim 1, wherein the fine space layer (50) is defined between a photonic plate (200) and the organic electroluminescence display portion, and wherein the photonic plate (200) has the diffraction grating (210; 220).

5. The organic electroluminescence display device assembly of claim 4, wherein the diffraction grating (210) comprises a plurality of protrusions formed on the lower surface of the photonic plate (200) with a predetermined pitch between adjacent protrusions.

6. An organic electroluminescence display device assembly according to claim 1, further comprising a driving portion (170) formed on the substrate (151) and having thin film transistors to switch the first electrode layer (161), wherein the organic electroluminescence portion defines a pixel portion (160) having the first electrode layer (161) patterned on the driving portion (170), the organic luminescent layer (162) patterned on an upper surface of the first electrode layer (161), an insulating layer formed on an upper surface of the organic luminescent layer (162) to expose the organic luminescent layer (162), and the second electrode layer (163) which is transparent and patterned on the upper surface of the organic luminescent layer (162) and an upper surface of the insulating layer, wherein the fine space layer (50) is defined between a photonic plate (200) and an upper surface of the second electrode layer (163), wherein the photonic plate has the diffraction grating (100, 120).

7. The organic electroluminescence display device assembly of claim 6, further comprising a planarization film formed on the lower surface of the first electrode layer (161).

8. The organic electroluminescence display device assembly of claim 6 or 7, wherein the diffraction grating (100) comprises a plurality of protrusions (111) formed on the lower surface of the photonic plate (200) with a predetermined pitch between adjacent protrusions.

9. The organic electroluminescence display device assembly of claim 3 or 5, wherein the protrusions (111) contact the second electrode layer (22; 74).
- 5 10. The organic electroluminescence display device assembly of any one of claims 3, 5, 8 or 9, wherein the pitch between adjacent protrusions (111) is 200 nm to 2000 nm.
11. The organic electroluminescence display device assembly of any one of claims 3, 5, 8, 9 or 10, wherein the height of each of the protrusions (111) is 50 nm to 5000 nm.
- 10 12. The organic electroluminescence display device assembly of claim 4 or 5, wherein the second electrode layer (74) is formed of indium tin oxide.
13. The organic electroluminescence display device assembly of any one of the preceding claims, wherein the diffraction grating (100 210) is formed of at least one material selected from the group consisting of SiO_x where $x > 1$, SiN_x ,
15 Si_3N_4 , TiO_2 , MgO , ZnO , Al_2O_3 , SnO_2 , In_2O_3 , MgF_2 , and CaF_2 .
14. The organic electroluminescence display device assembly of claim 13, wherein the optical loss prevention layer (100; 210) is formed of TiO_2 .
- 20 15. The organic electroluminescence display device assembly of any one of the preceding claims, further comprising an index layer (60) having a refractive index greater than or equal to 2.3 formed between the fine space layer (50) and the first or second electrode layer (22; 163).
- 25 16. The organic electroluminescence display device assembly of claim 15, wherein the index layer (60) is formed of TiO_2 .
17. The organic electroluminescence display device assembly of claim 15 or 16, wherein the thickness of the index layer (60) is greater than or equal to 2000 nm.
- 30 18. An organic electroluminescence display device assembly according to claim 2, wherein the diffraction grating (120) is formed between the first electrode layer (22) and the substrate (21) and the fine space layer (50) is formed between the diffraction grating (120) and the first electrode layer (22),
and wherein the diffraction grating (120) is a patterned thin film having a substantially different refractive index from a refractive index of the first electrode layer (22), the organic luminescent layer (30) and/or the second electrode layer (23), the thin film comprising at least two area groups having different refractive indices, a pitch (P) between
35 adjacent areas in one of the two area groups being in the range 50 nm to 3000 nm.
19. The organic electroluminescence display device assembly of claim 18, wherein the thickness of the diffraction grating (120) is in the range of 0.01 μm to 50 μm .
- 40 20. The organic electroluminescence display device assembly of claim 18 or 19, wherein the diffraction grating (120) is formed of inorganic materials with refractive indices that differ by an amount in a range of 0.3 to 3.
21. The organic electroluminescence display device assembly of claim 20, wherein the inorganic materials are at least two materials selected from the group consisting of SiO_x ($x > 1$), SiN_x , Si_3N_4 , TiO_2 , MgO , ZnO , Al_2O_3 , SnO_2 , In_2O_3 ,
45 MgF_2 , and CaF_2 .
22. An organic electroluminescence display device assembly according to claim 6:
further comprising a planarization film formed on the upper surface of the second electrode layer (163); and
50 wherein the photonic plate (200) defines the fine space layer (50) by combination with the planarization film and wherein the diffraction grating (120) has patterned areas with different refractive indices.
23. The organic electroluminescence display device assembly of claim 22, further comprising an index layer (60) having a refractive index greater than or equal to 2.3 formed between the fine space layer (50) and the second electrode layer (163).
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24. The organic electroluminescence display device assembly of any of claims 18 to 23, wherein the diffraction grating (120) is a patterned thin film having at least two materials with different refractive indices.

25. The organic electroluminescence display device assembly of claim 24, wherein the pitch (P) between adjacent areas with different refractive indices of the diffraction grating (120) is in the range of 50 nm to 3000 nm.

5 **Patentansprüche**

1. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit, umfassend:

ein Substrat (21; 71); und

10 einen organischen Elektrolumineszenz-Abschnitt mit einer ersten Elektrodenschicht (22; 72), einer organischen Lumineszenzschicht (30; 73) und einer zweiten Elektrodenschicht (23; 74), die jeweils gemustert und auf einer oberen Oberfläche des Substrats (21; 71) gestapelt sind; und

ein Beugungsgitter (100; 120; 210; 220), das auf der oberen Oberfläche des Substrats oberhalb oder unterhalb des organischen Elektrolumineszenz-Abschnitts gestapelt oder proximal dazu angeordnet ist, um als eine optische Verlustverhinderungsschicht zu fungieren, um die Light Bleeding-Effizienz zu erhöhen;

15 **dadurch gekennzeichnet, dass** eine mit einem Gas gefüllte oder evakuierte feine Abstandsschicht (50) zwischen dem Beugungsgitter (100; 120; 210; 220) und dem organischen Elektrolumineszenz-Abschnitt ausgebildet ist.

- 20 2. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 1, wobei die erste Elektrodenschicht (22), die organische Lumineszenzschicht (30) und die zweite Elektrodenschicht (23) jeweils gemustert und proximal zu einer oberen Oberfläche des Substrats (21) gestapelt sind.

- 25 3. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 2, wobei das Beugungsgitter (100) eine Mehrzahl von Vorsprüngen (111) aufweist, die auf der oberen Oberfläche des Substrats (21) ausgebildet sind, mit einem vorbestimmten Abstand (P) zwischen benachbarten Vorsprüngen (111)

- 30 4. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 1, wobei die feine Abstandsschicht (50) definiert ist zwischen einer photonischen Platte (200) und dem organischen Elektrolumineszenz-Anzeigeabschnitt, und wobei die photonische Platte (200) das Beugungsgitter (210; 220) aufweist.

5. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 4, wobei das Beugungsgitter (210) eine Mehrzahl von Vorsprüngen aufweist, die auf der unteren Oberfläche der photonischen Platte (200) ausgebildet sind, mit einem vorbestimmten Abstand zwischen benachbarten Vorsprüngen.

- 35 6. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 1, ferner umfassend einen auf dem Substrat (151) ausgebildeten Steuerabschnitt (170) und mit Dünnschichttransistoren, um Schalten der ersten Elektrodenschicht (161),

wobei der organische Elektrolumineszenz-Abschnitt einen Pixelabschnitt (160) definiert, wobei die erste Elektrodenschicht (161) auf dem Steuerabschnitt (170) gemustert ist, wobei die organische Lumineszenzschicht (162) auf einer oberen Oberfläche der ersten Elektrodenschicht (161) gemustert ist, wobei eine isolierende Schicht auf einer oberen Oberfläche der organischen Lumineszenzschicht (162) ausgebildet ist, um die organische Lumineszenzschicht (162) und die zweite Elektrodenschicht (163) zu exponieren, die transparent ist und auf der oberen Oberfläche der organischen Lumineszenzschicht (162) und einer oberen Oberfläche der isolierenden Schicht gemustert ist;

40 wobei die feine Abstandsschicht (50) definiert ist zwischen einer photonischen Platte (200) und einer oberen Oberfläche der zweiten Elektrodenschicht (163), wobei die photonische Platte das Beugungsgitter (100, 120) aufweist.

7. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 6, ferner umfassend eine Planarisierungsschicht, die auf der unteren Oberfläche der ersten Elektrodenschicht (161) ausgebildet ist.

- 50 8. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 6 oder 7, wobei das Beugungsgitter (100) eine Mehrzahl von Vorsprüngen (111) umfasst, die auf der unteren Oberfläche der photonischen Platte (200) ausgebildet sind, mit einem vorbestimmten Abstand zwischen benachbarten Vorsprüngen.

- 55 9. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 3 oder 5, wobei die Vorsprünge (111) die zweite Elektrodenschicht (22; 74) berühren.

10. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach einem der Ansprüche 3, 5, 8 oder 9, wobei der Abstand zwischen benachbarten Vorsprüngen (111) 200 nm bis 2000 nm beträgt.

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11. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach einem der Ansprüche 3, 5, 8, 9 oder 10, wobei die Höhe jedes der Vorsprünge (111) zwischen 50 nm und 5000 nm liegt.
- 5 12. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 4 oder 5, wobei die zweite Elektroden-
schicht (74) aus Indiumzinnoxid besteht.
- 10 13. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach einem der vorstehenden Ansprüche, wobei das
Beugungsgitter (100, 210) aus wenigstens einem Material besteht, das ausgewählt ist aus der Gruppe bestehend
aus SiO_x , wobei $x > 1$, SiN_x , Si_3N_4 , TiO_2 , MgO , ZnO , Al_2O_3 , SnO_2 , In_2O_3 , MgF_2 und CaF_2 .
- 15 14. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 13, wobei die optische Verlustverhin-
derungsschicht (100; 210) aus TiO_2 besteht.
- 20 15. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach einem der vorstehenden Ansprüche, ferner um-
fassend eine Indexschicht (60) mit einem Brechungsindex, der größer oder gleich 2,3 ist, ausgebildet zwischen der
feinen Abstandsschicht (50) und der ersten oder zweiten Elektroden-schicht (22, 163).
- 25 16. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 15, wobei die Indexschicht (60) aus
 TiO_2 besteht.
- 30 17. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 15 oder 16, wobei die Dicke der Index-
schicht (60) größer oder gleich 2000 nm ist.
- 35 18. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 2, wobei das Beugungsgitter (120) zwi-
schen der ersten Elektroden-schicht (22) und dem Substrat (21) ausgebildet ist, und wobei die feine Abstandsschicht
(50) zwischen dem Beugungsgitter (120) und der ersten Elektroden-schicht (22) ausgebildet ist;
und wobei das Beugungsgitter (120) eine gemusterte Dünnschicht ist, mit einem Brechungsindex, der sich substan-
tiell von dem Brechungsindex der ersten Elektroden-schicht (22), der organischen Lumineszenzschicht (30) und/oder
der zweiten Elektroden-schicht (23) unterscheidet, wobei die Dünnschicht mindestens zwei Bereichsgruppen mit
unterschiedlichen Brechungsindizes umfasst, wobei ein Abstand (P) zwischen benachbarten Bereichen in einer der
beiden Bereichsgruppen im Bereich von 50 nm bis 3000 nm liegt.
- 40 19. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 18, wobei die Dicke des Beugungsgit-
ters (120) im Bereich von 0,01 μm bis 50 μm liegt.
- 45 20. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 18 oder 19, wobei das Beugungsgitter
(120) aus anorganischen Substanzen mit Brechungsindizes besteht, die sich um 0,3 bis 3 unterscheiden.
- 50 21. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 20, wobei die anorganischen Substan-
zen wenigstens zwei Substanzen sind, die ausgewählt sind aus der Gruppe bestehend aus SiO_x ($x > 1$), SiN_x , Si_3N_4 ,
 TiO_2 , MgO , ZnO , Al_2O_3 , SnO_2 , In_2O_3 , MgF_2 und CaF_2 .
- 55 22. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 6:
ferner umfassend eine Planarisierungsschicht, die auf der oberen Oberfläche der zweiten Elektroden-schicht
(163) ausgebildet ist; und
wobei die photonische Platte (200) eine feine Abstandsschicht (50) definiert durch Kombination mit der Plana-
risierungsschicht, und wobei das Beugungsgitter (120) gemusterte Bereiche mit unterschiedlichen Brechungs-
indizes aufweist.
23. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 22, ferner umfassend eine Indexschicht
(60) mit einem Brechungsindex von größer oder gleich 2,3, ausgebildet zwischen der feinen Abstandsschicht (50)
und der zweiten Elektroden-schicht (163).
24. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach einem der Ansprüche 18 bis 23, wobei das Beu-
gungsgitter (120) eine gemusterte Dünnschicht mit mindestens zwei Materialien mit unterschiedlichen Brechungs-
indizes ist.

25. Organische Elektrolumineszenz-Anzeigevorrichtungseinheit nach Anspruch 24, wobei der Abstand (P) zwischen benachbarten Bereichen mit unterschiedlichen Brechungsindizes im Bereich von 50 nm bis 3000 nm liegt.

5 **Revendications**

1. Ensemble dispositif d'affichage électroluminescent organique comprenant :
- 10 un substrat (21 ; 71) ; et
 une partie électroluminescente organique ayant une première couche d'électrode (22 ; 72), une couche lumineuse organique (30 ; 73), et une seconde couche d'électrode (23 ; 74), qui sont chacune à motifs et empilées sur une surface supérieure du substrat (21 ; 71) ; et
 un réseau de diffraction (100 ; 120 ; 210 ; 220) empilé sur ou à proximité de la surface supérieure du substrat au-dessus ou en dessous de la partie électroluminescente organique conçu pour fonctionner comme une couche
 15 de prévention de perte optique pour augmenter l'efficacité de passage de la lumière ;
caractérisé en ce qu'une mince couche d'espace (50) remplie d'un gaz ou sous vide est formée entre le réseau de diffraction (100 ; 120 ; 210 ; 220) et la partie électroluminescente organique.
2. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 1, la première couche d'électrode (22), la couche lumineuse organique (30), et la seconde couche d'électrode (23) étant chacune à motifs et empilées à proximité d'une surface supérieure du substrat (21).
- 20 3. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 2, le réseau de diffraction (100) ayant une pluralité de saillies (111) formées sur la surface supérieure du substrat (21) avec un pas (P) prédéterminé entre des saillies (111) adjacentes.
- 25 4. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 1, la mince couche d'espace (50) étant définie entre une plaque photonique (200) et la partie d'affichage électroluminescent organique, et la plaque photonique (200) ayant le réseau de diffraction (210 ; 220).
- 30 5. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 4, le réseau de diffraction (210) comprenant une pluralité de saillies formées sur la surface inférieure de la plaque photonique (200) avec un pas prédéterminé entre des saillies adjacentes.
- 35 6. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 1, comprenant en outre une partie d'entraînement (170) formée sur le substrat (151) et ayant des transistors à couches minces pour commuter la première couche d'électrode (161),
 la partie électroluminescente organique définissant une partie de pixel (160) ayant la première couche d'électrode (161) à motifs sur la partie d'entraînement (170), la couche lumineuse organique (162) à motifs sur une surface
 40 supérieure de la première couche d'électrode (161), une couche isolante formée sur une surface supérieure de la couche lumineuse organique (162) pour exposer la couche lumineuse organique (162), et la seconde couche d'électrode (163) qui est transparente et à motifs sur la surface supérieure de la couche lumineuse organique (162) et une surface supérieure de la couche isolante,
 la mince couche d'espace (50) étant définie entre une plaque photonique (200) et une surface supérieure de la
 45 seconde couche d'électrode (163), la plaque photonique ayant le réseau de diffraction (100, 120).
7. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 6, comprenant en outre un film de planarisation formé sur la surface inférieure de la première couche d'électrode (161).
- 50 8. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 6 ou 7, le réseau de diffraction (100) comprenant une pluralité de saillies (111) formées sur la surface inférieure de la plaque photonique (200) avec un pas prédéterminé entre des saillies adjacentes.
9. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 3 ou 5, les saillies (111) étant
 55 en contact avec la seconde couche d'électrode (22 ; 74).
10. Ensemble dispositif d'affichage électroluminescent organique selon l'une quelconque des revendications 3, 5, 8 ou 9, le pas entre des saillies adjacentes (111) étant de 200 à 2 000 nm.

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11. Ensemble dispositif d'affichage électroluminescent organique selon l'une quelconque des revendications 3, 5, 8, 9 ou 10, la hauteur de chacune des saillies (111) étant de 50 à 5 000 nm.
- 5 12. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 4 ou 5, la seconde couche d'électrode (74) étant formée d'oxyde d'indium et d'étain.
- 10 13. Ensemble dispositif d'affichage électroluminescent organique selon l'une quelconque des revendications précédentes, le réseau de diffraction (100, 210) étant formé d'au moins un matériau choisi dans le groupe constitué de SiO_x où $x > 1$, SiN_x , Si_3N_4 , TiO_2 , MgO , ZnO , Al_2O_3 , SnO_2 , In_2O_3 , MgF_2 , et CaF_2 .
- 15 14. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 13, la couche de prévention de perte optique (100 ; 210) étant formée de TiO_2 .
- 20 15. Ensemble dispositif d'affichage électroluminescent organique selon l'une quelconque des revendications précédentes, comprenant en outre une couche d'indice (60) ayant un indice de réfraction supérieur ou égal à 2,3 formée entre la mince couche d'espace (50) et la première ou seconde couche d'électrode (22 ; 163).
- 25 16. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 15, la couche d'indice (60) étant formée de TiO_2 .
- 30 17. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 15 ou 16, l'épaisseur de la couche d'indice (60) étant supérieure ou égale à 2 000 nm.
- 35 18. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 2, le réseau de diffraction (120) étant formé entre la première couche d'électrode (22) et le substrat (21) et la mince couche d'espace (50) étant formée entre le réseau de diffraction (120) et la première couche d'électrode (22), et le réseau de diffraction (120) étant un film mince à motifs ayant un indice de réfraction sensiblement différent d'un indice de réfraction de la première couche d'électrode (22), de la couche luminescente organique (30) et/ou de la seconde couche d'électrode (23), le film mince comprenant au moins deux groupes de zones ayant des indices de réfraction différents, un pas (P) entre des zones adjacentes dans l'un des deux groupes de zones étant de 50 à 3 000 nm.
- 40 19. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 18, l'épaisseur du réseau de diffraction (120) étant de 0,01 à 50 μm .
- 45 20. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 18 ou 19, le réseau de diffraction (120) étant formé de matériaux inorganiques ayant des indices de réfraction qui diffèrent de 0,3 à 3.
- 50 21. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 20, les matériaux inorganiques étant au moins deux matériaux choisis dans le groupe constitué de SiO_x ($x > 1$), SiN_x , Si_3N_4 , TiO_2 , MgO , ZnO , Al_2O_3 , SnO_2 , In_2O_3 , MgF_2 et CaF_2 .
- 55 22. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 6 :
comprenant en outre un film de planarisation formé sur la surface supérieure de la seconde couche d'électrode (163) ; et
la plaque photonique (200) définissant la mince couche d'espace (50) en combinaison avec le film de planarisation et le réseau de diffraction (120) ayant des zones à motif ayant différents indices de réfraction.
23. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 22, comprenant en outre une couche d'indice (60) ayant un indice de réfraction supérieur ou égal à 2,3 formée entre la mince couche d'espace (50) et la seconde couche d'électrode (163).
24. Ensemble de dispositif d'affichage électroluminescent organique selon l'une quelconque des revendications 18 à 23, le réseau de diffraction (120) étant un film mince à motifs ayant au moins deux matériaux ayant différents indices de réfraction.
25. Ensemble dispositif d'affichage électroluminescent organique selon la revendication 24, le pas (P) entre des zones

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adjacentes ayant différents indices de réfraction du réseau de diffraction (120) étant de 50 à 3 000 nm.

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FIG. 1 (PRIOR ART)

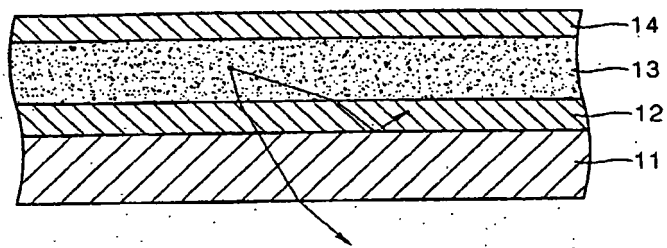


FIG. 2

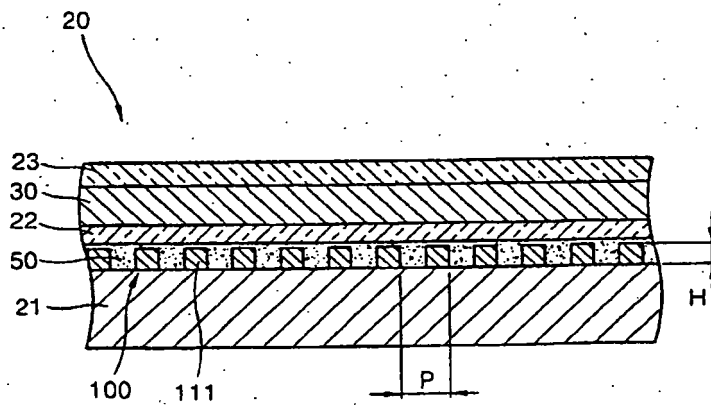


FIG. 3

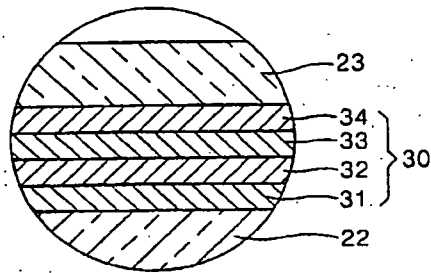


FIG. 4

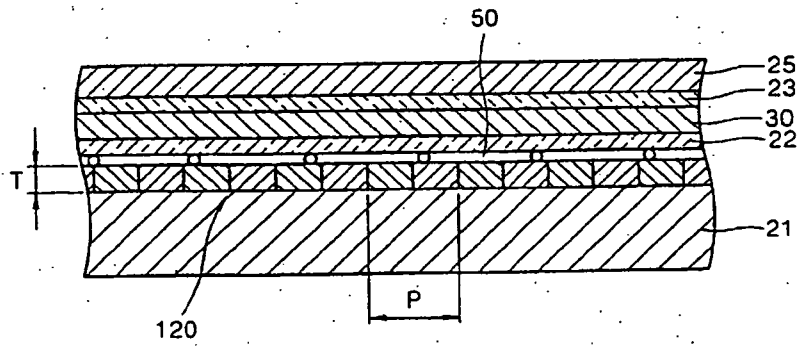


FIG. 5

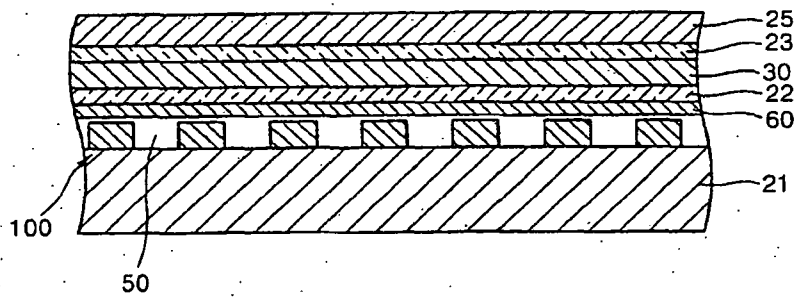


FIG. 6

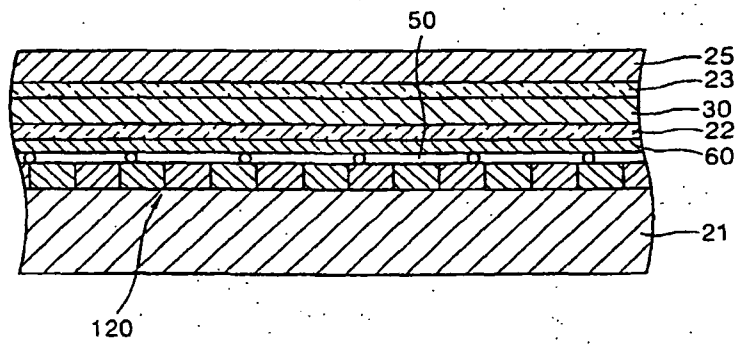


FIG. 7

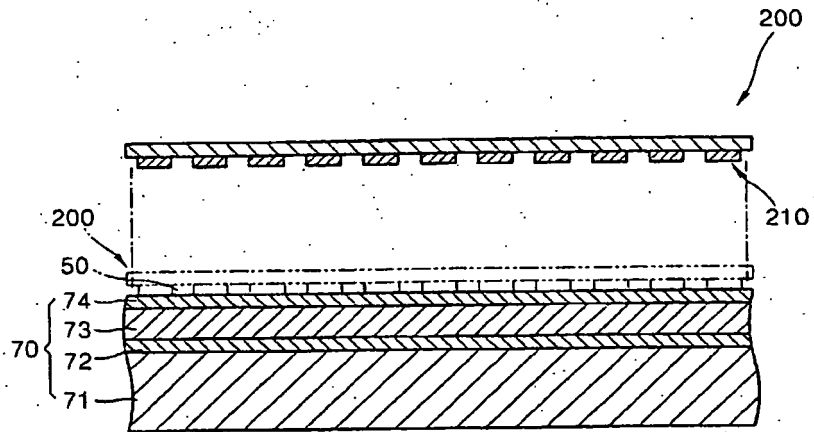


FIG. 8

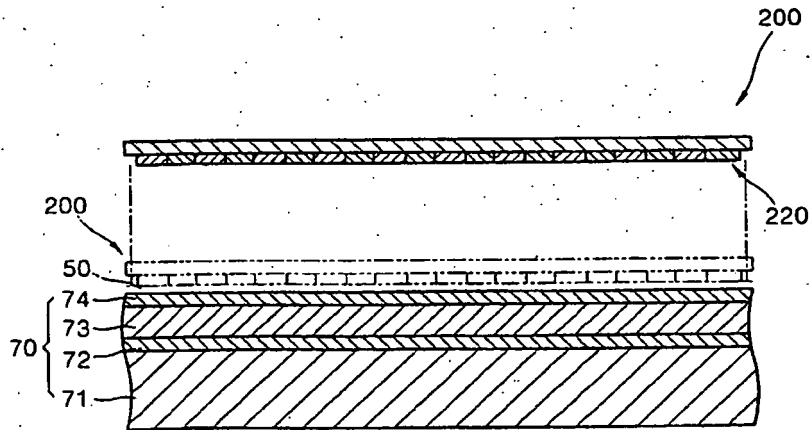


FIG. 9

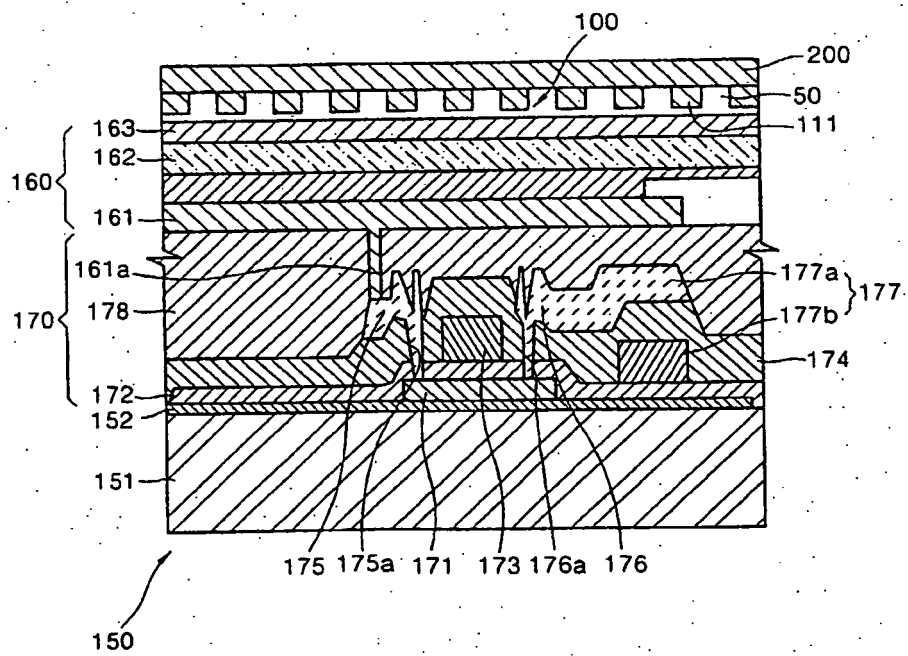


FIG. 10

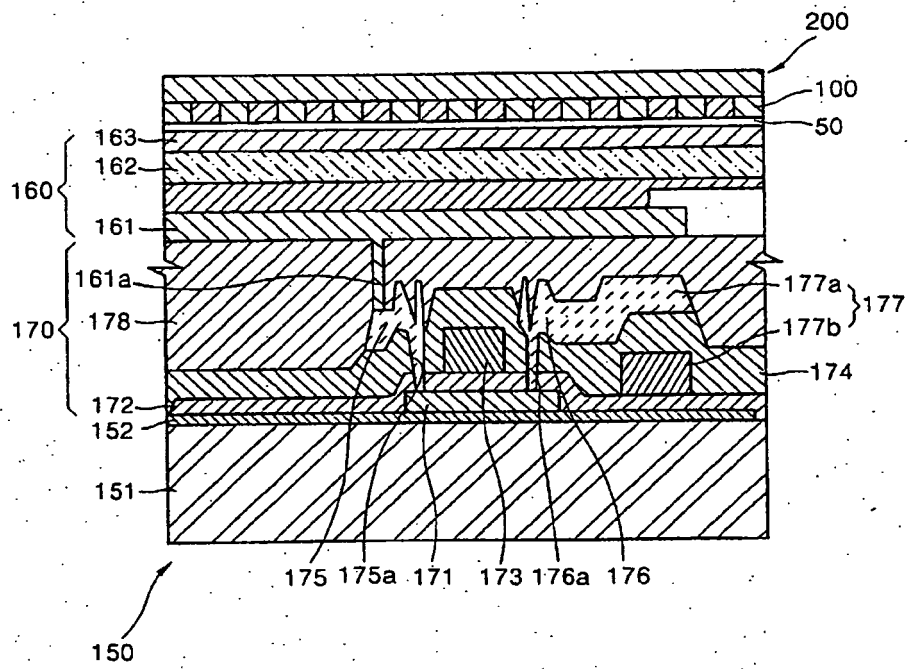


FIG. 11

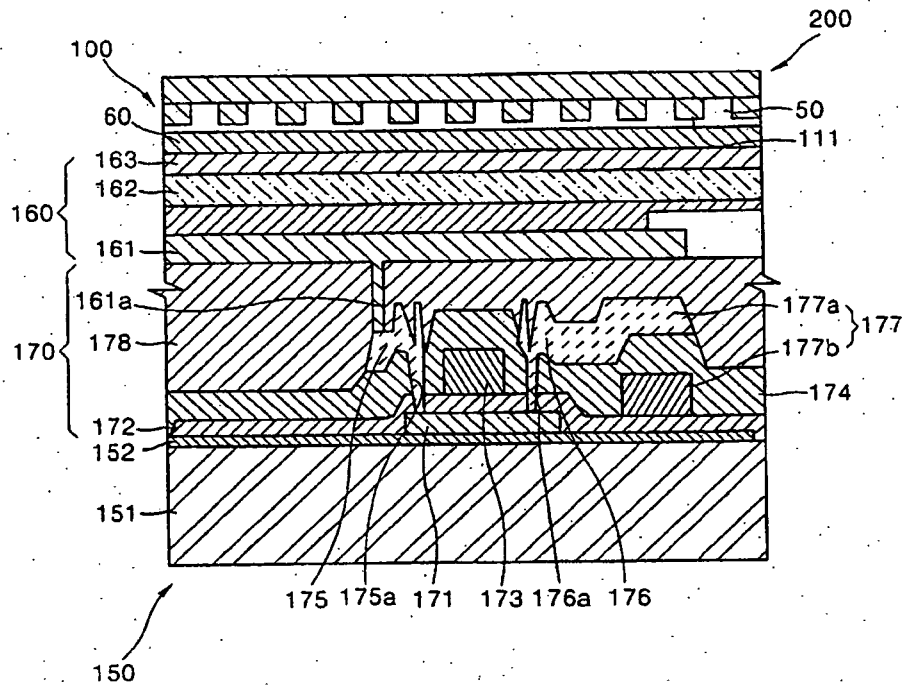


FIG. 12

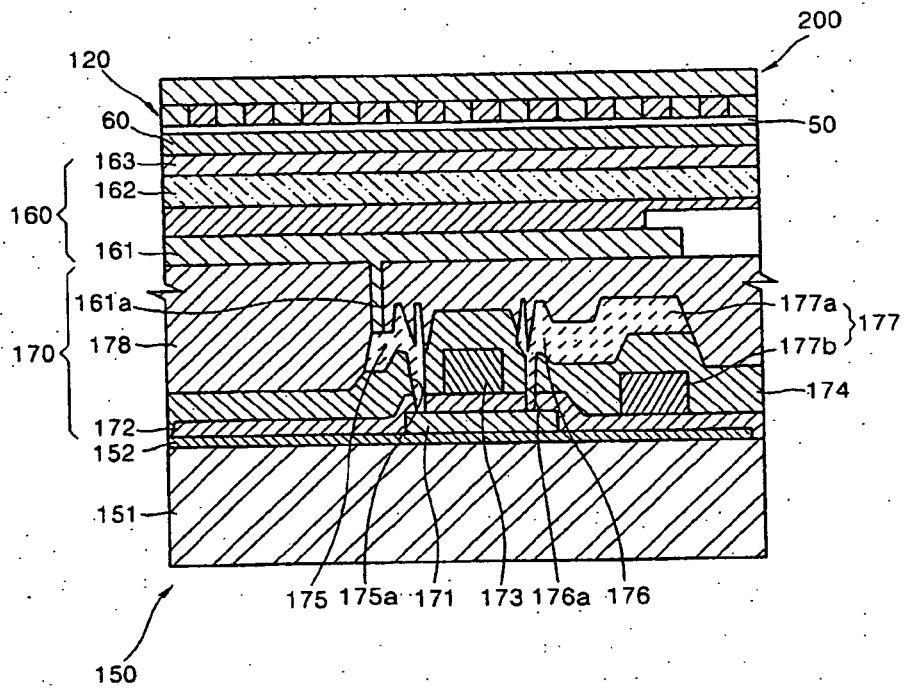


FIG. 13

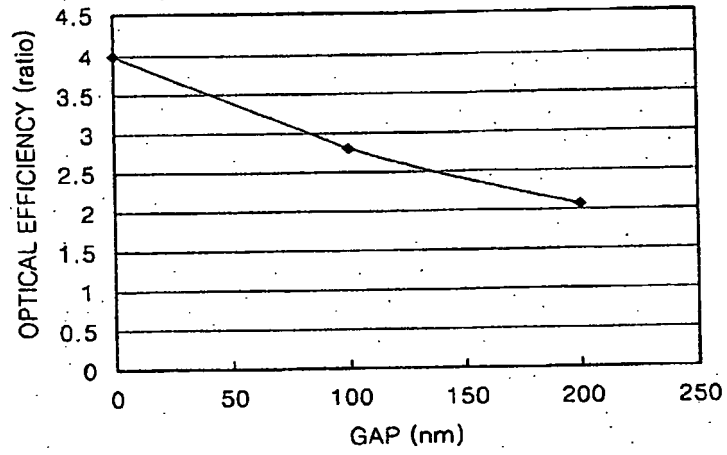


FIG. 14

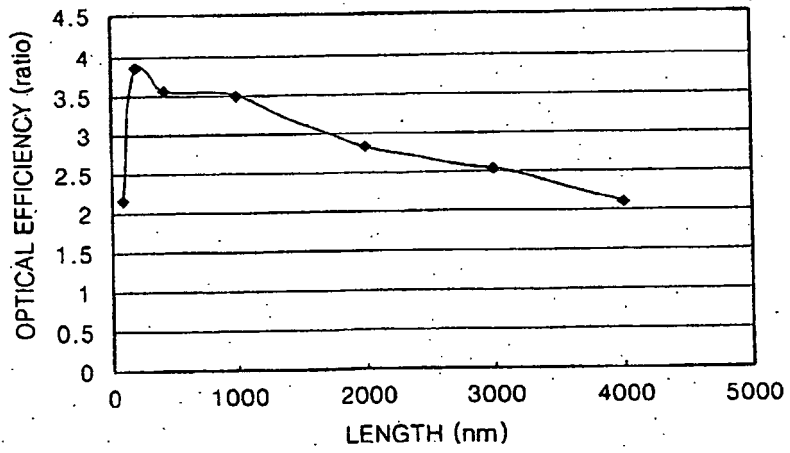


FIG. 15

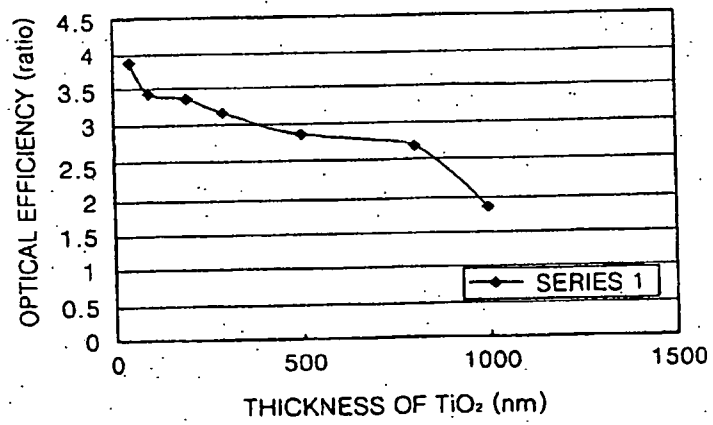


FIG. 16

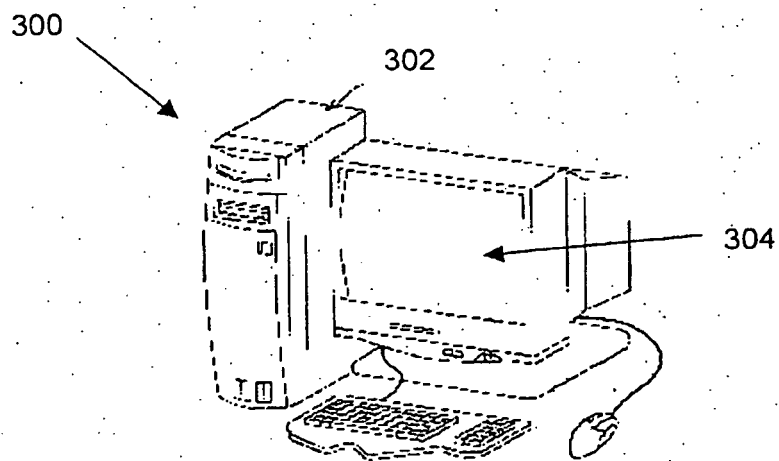
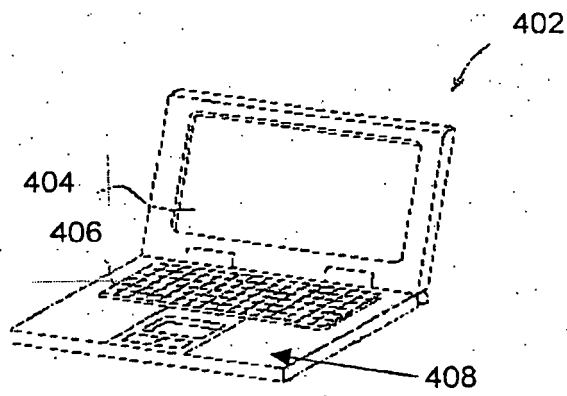


FIG. 17



REFERENCES CITED IN THE DESCRIPTION

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优先权	1020030014000 2003-03-06 KR		
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摘要(译)

有机电致发光 (EL) 显示装置组件包括基板, 有机EL部分, 光学损失防止层和精细空间层。有机EL部分具有第一电极层, 有机发光层和第二电极层, 它们各自图案化并堆叠在基板的上表面上。光学损失防止层用于增加光出射效率。微小空间层形成在光学防损层和面向光学防损层的层之间, 并填充有气体或抽空。

FIG. 1 (PRIOR ART)

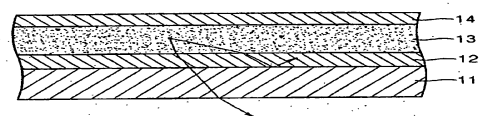


FIG. 2

